

August 1990 Revised February 2005

74ACTQ00

Quiet Series™ Quad 2-Input NAND Gate

General Description

The ACTQ00 contains four 2-input NAND gates and utilizes Fairchild FACT Quiet Series™ technology to guarantee quiet output switching and improve dynamic threshold performance FACT Quiet Series features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

Features

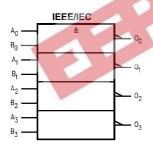
- I_{CC} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- Has TTL-compatible inputs

Ordering Code:

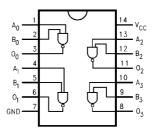
Order Number	Package Number	Package Description					
74ACTQ00SC	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow					
74ACTQ00MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide					
74ACTQ00PC	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide					

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering co

Logic Symbol



Connection Diagram



Pin Descriptions

Pin Names	Description				
A _n , B _n	Inputs				
\overline{O}_n	Outputs				

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Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5 V to +7.0 V DC Input Diode Current (I_{IK})

 $\begin{array}{c} \text{V}_{\text{I}} = -0.5 \text{V} & -20 \text{ mA} \\ \text{V}_{\text{I}} = \text{V}_{\text{CC}} + 0.5 \text{V} & +20 \text{ mA} \\ \\ \text{DC Input Voltage (V_{\text{I}})} & -0.5 \text{V to V}_{\text{CC}} + 0.5 \text{V} \\ \end{array}$

DC Output Diode Current (I_{OK})

 $\begin{array}{ccc} \rm V_O = -0.5V & -20~mA \\ & \rm V_O = V_{CC} + 0.5V & +20~mA \\ DC~Output~Voltage~(V_O) & -0.5V~to~V_{CC} + 0.5V \\ DC~Output~Source & \end{array}$

or Sink Current (I_O)
DC V_{CC} or Ground Current

per Output Pin (I_{CC} or I_{GND}) ± 50 mA Storage Temperature (T_{STG}) -65° C to $+150^{\circ}$ C

DC Latch-up Source

or Sink Current ±300 mA

Junction Temperature (T_J)

PDIP 140°C

Recommended Operating Conditions

Minimum Input Edge Rate ($\Delta V/\Delta t$)

 V_{IN} from 0.8V to 2.0V 125 mV/ns

V_{CC} @ 4.5V, 5.5V

±50 mA

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside databook specifications.

DC Electrical Characteristics

Symbol	Parameter	v _{cc}	$T_A = +25^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			Units	Conditions	
Oyiliboi	rarameter	(V)	Typ Guaranteed Limits			Onits		
V _{IH}	Minimum HIGH Level	4.5	1.5	2.0	2.0	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	1.5	2.0	2.0	v	or V _{CC} – 0.1V	
V _{IL}	Maximum LOW Level	4.5	1.5	0.8	0.8	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	1.5	0.8	0.8	v	or V _{CC} – 0.1V	
V _{OH}	Minimum HIGH Level	4.5	4.49	4.4	4.4	٧	I _{OUT} = -50 μA	
	Output Voltage	5.5	5.49	5.4	5.4	v	1001 = -20 trv	
							$V_{IN} = V_{IL} \text{ or } V_{IH}$	
		4.5		3.86	3.76	V	$I_{OH} = -24 \text{ mA}$	
		5.5		4.86	4.76		I _{OH} = -24 mA (Note 2)	
V _{OL}	Maximum LOW Level	4.5	0.001	0.1	0.1	V	I _{OUT} = 50 μA	
	Output Voltage	5.5	0.001	0.1	0.1	v		
							V _{IN} = V _{IL} or V _{IH}	
		4.5		0.36	0.44	V	$I_{OL} = 24 \text{ mA}$	
		5.5		0.36	0.44		I _{OL} = 24 mA (Note 2)	
I _{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	μА	$V_I = V_{CC}$, GND	
I _{CCT}	Maximum I _{CC} /Input	5.5	0.6		1.5	mA	$V_{I} = V_{CC} - 2.1V$	
I _{OLD}	Minimum Dynamic	5.5			75	mA	V _{OLD} = 1.65V Max	
I _{OHD}	Output Current (Note 3)	5.5			-75	mA	V _{OHD} = 3.85V Min	
Icc	Maximum Quiescent Supply Current	5.5		2.0	20.0	μА	$V_{IN} = V_{CC}$ or GND	
V _{OLP}	Quiet Output Maximum Dynamic	5.0	1.1	1.5		V	Figure 1, Figure 2	
	V_{OL}						(Note 4)(Note 5)	
V _{OLV}	Quiet Output Minimum Dynamic	5.0	-0.6	-1.2		V	Figure 1, Figure 2	
	V _{OL} 5.0		-0.6	-1.2		v	(Note 4)(Note 5)	
V _{IHD}	Minimum HIGH Level	5.0	1.9	2.2		V	(Note 4)(Note 6)	
	Dynamic Input Voltage							
V _{ILD}	Maximum LOW Level	5.0	1.2	0.8		V	(Note 4)(Note 6)	
	Dynamic Input Voltage							

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: DIP package.

 $\textbf{Note 5:} \ \textbf{Max number of outputs defined as (n).} \ \textbf{Data inputs are 0V to 3V.} \ \textbf{One output} \ @ \ \textbf{GND.}$

Note 6: Max number of data inputs (n) switching. (n-1) inputs switching 0V to 3V. Input-under-test switching: 3V to threshold (V_{ILD}) , 0V to threshold (V_{IHD}) , f = 1 MHz.

AC Electrical Characteristics

Symbol	Parameter	V _{CC} (V)	$T_A = +25$ °C $C_L = 50 \text{ pF}$			$T_A = -40$ °C to +85°C $C_L = 50$ pF		Units
		(Note 7)	Min	Тур	Max	Min	Max	
t _{PLH}	Propagation Delay Data to Output	5.0	2.0		7.5	2.0	8.0	ns
t _{PHL}	Propagation Delay Data to Output	5.0	2.0		7.5	2.0	8.0	ns
t _{OSHL}	Output to Output Skew (Note 8)	5.0		0.5	1.0		1.0	ns

Note 7: Voltage Range 5.0 is $5.0V \pm 0.5V$.

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
CPD	Power Dissipation Capacitance	74	pF	$V_{CC} = 5.0V$



FACT™ Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of FACT.

Equipment:

Hewlett Packard Model 8180A Word Generator PC-163A Test Fixture

Tektronics Model 7854 Oscilloscope

Procedure:

- 1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω .
- Deskew the HFS generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. It is important to deskew the word generator channels before testing. This will ensure that the outputs switch simultaneously.
- Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
- Set the HFS generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and effect the results of the measurement
- Set the HFS generator input levels at 0V LOW and 3V HIGH for ACT devices and 0V LOW and 5V HIGH for AC devices. Verify levels with an oscilloscope



Note 10: Input pulses have the following characteristics: f = 1 MHz, $t_f = 3$ ns, $t_f = 3$ ns, skew < 150 ps.

FIGURE 1. Quiet Output Noise Voltage Waveforms

V_{OLP}/V_{OLV} and V_{OHP}/V_{OHV}:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the worst case transition for active and enable. Measure V_{OHP} and V_{OHV} on the quiet output during the worst case active and enable transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD}:

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate or steps out a min of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level.V_{IH} until the output begins to oscillate or steps out a mine of 2 ns. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

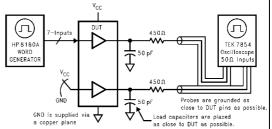
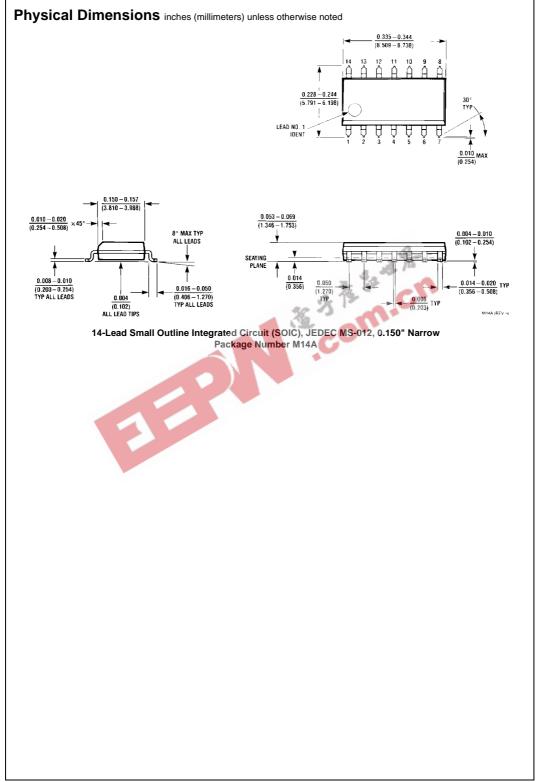
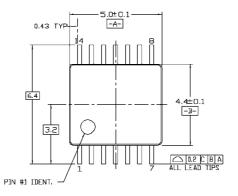
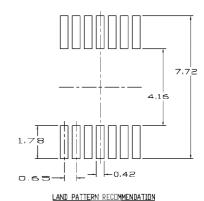


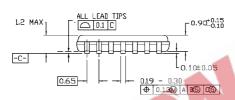
FIGURE 2. Simultaneous Switching Test Circuit



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)









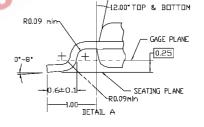
NOTES:

- A. CONFORMS TO JEDEC REGISTRATION MO-153 VARIATION AB-REF NOTE 6, DATED 7/93

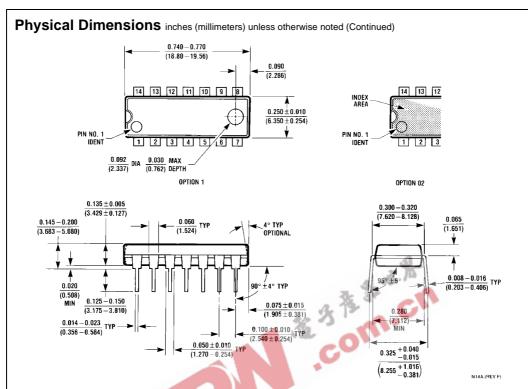
 B. DIMENSIONS ARE IN MILLIMETERS

 C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
 D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982

MTC14revD



14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide Package Number MTC14



14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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